

**BT234W-800ET** 

4Q Triac Rev.01 - 09 January 2025

**Product data sheet** 

### **1. General description**

Planar passivated sensitive gate four quadrant triac in a SOT223 surface-mountable plastic package. This sensitive gate triac is intended for interfacing with low power drivers including microcontrollers.

### 2. Features and benefits

- Direct interfacing to logic level ICs
- · Direct interfacing to low power gate drivers and microcontrollers
- High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Sensitive gate
- Surface-mountable package
- Triggering in all four quadrants

### 3. Applications

- General purpose low power motor control
- General purpose switching and phase control

### 4. Quick reference data

Symbol	Parameter	Conditions	Notes		Values	;	Unit
Absolute	e maximum rating						
$V_{\text{DRM}}$	repetitive peak off-state voltage				800		V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>sp</sub> ≤ 67 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>			4		A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 4; Fig. 5</u>		25			A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms			27		А
Tj	operating junction temperature			-40 to 150		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; Fig. 9		-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. 9}$		-	-	10	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G+; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	-	25	mA

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Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
Static cha	Static characteristics							
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>		-	-	15	mA	
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 12</u>		-	1.4	1.6	V	
Dynamic	Dynamic characteristics							
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit		30	-	-	V/µs	

### **5. Pinning information**

#### Table 2. Pinning information Pin Symbol **Simplified outline Description Graphic symbol** 1 Τ1 main terminal 1 4 T2 2 main terminal 2 G gate sym051 3 G T2 main terminal 2 4 -2 3

### 6. Ordering information

### Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BT234W-800ET	SOT223	BT234W-800ETF	Reel	4000	SOT223	16-Mar-2006

### 7. Marking

#### Table 4. Marking codes

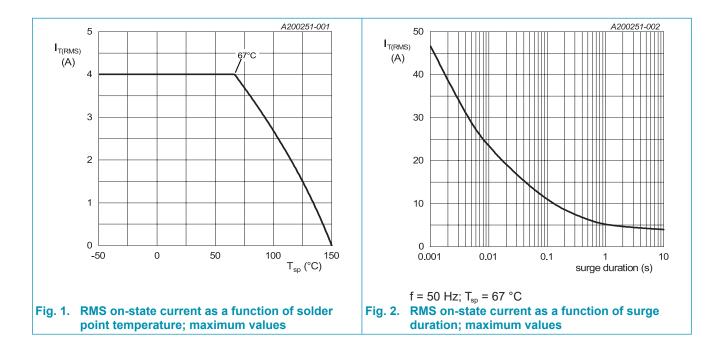
Type number	Marking codes			
	Assembly factory: d	Assembly factory: L		
BT234W-800ET	Jdxxx 234W8E	JLxxx 234W8E		

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

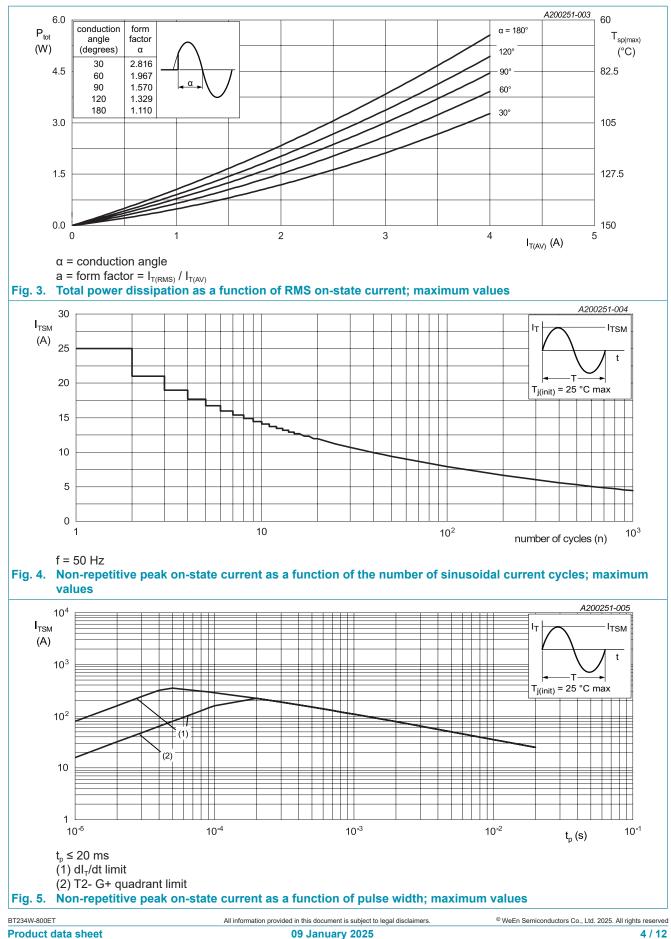
Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage			800	V
$V_{\text{RRM}}$	repetitive peak reverse voltage			800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T <sub>sp</sub> ≤ 67 °C; <u>Fig 1; Fig 2</u> ; <u>Fig 3</u>		4	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 20 ms; Fig 4; Fig 5		25	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms		27	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN		3.1	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 20 mA; T2+ G+		50	A/µs
		I <sub>G</sub> = 20 mA; T2+ G-		50	A/µs
		I <sub>G</sub> = 20 mA; T2- G-		50	A/µs
		I <sub>G</sub> = 50 mA; T2- G+		10	A/µs
I <sub>GM</sub>	peak gate current			2	А
P <sub>GM</sub>	peak gate power			5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period		0.5	W
T <sub>stg</sub>	storage temperature			-40 to 150	°C
T <sub>j</sub>	operating junction temperature			-40 to 150	°C



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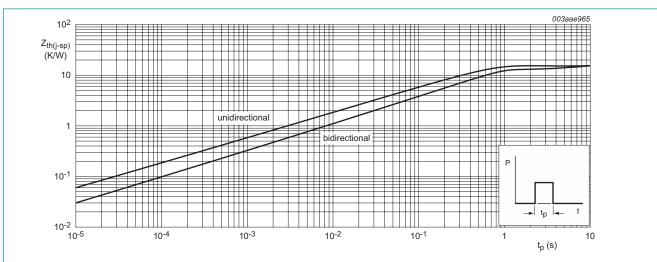
**4Q Triac** 



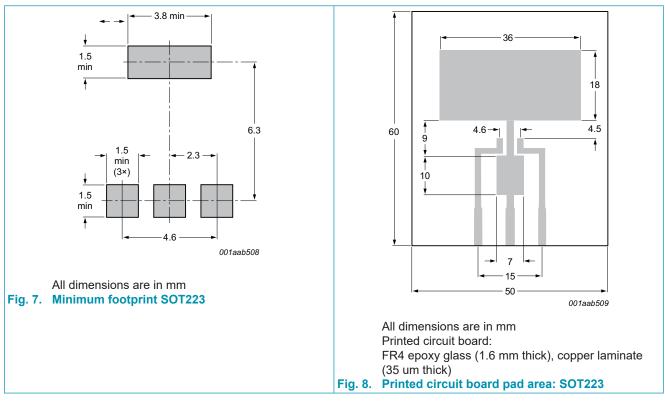
### 9. Thermal characteristics

### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	full cycle; <u>Fig 6</u>		-	-	15	K/W
R <sub>th(j-a)</sub> thermal resistance from junction to ambient		full cycle; printed circuit board mounted; minimum footprint; <u>Fig 7</u>		-	156	-	K/W
		full cycle; printed circuit board mounted; pad area; Fig 8		-	70	-	K/W



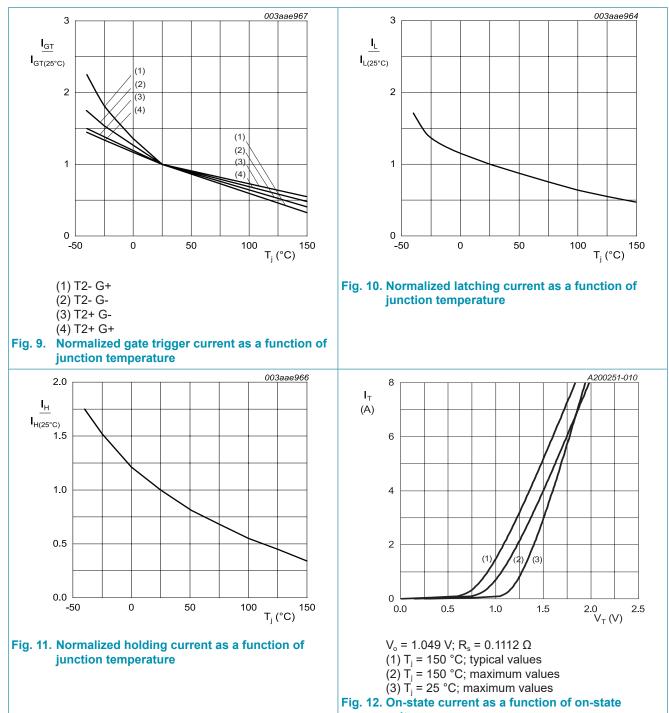
### Fig. 6. Transient thermal impedance from junction to solder point as a function of pulse width



### **10. Characteristics**

Table 7. Characteristics

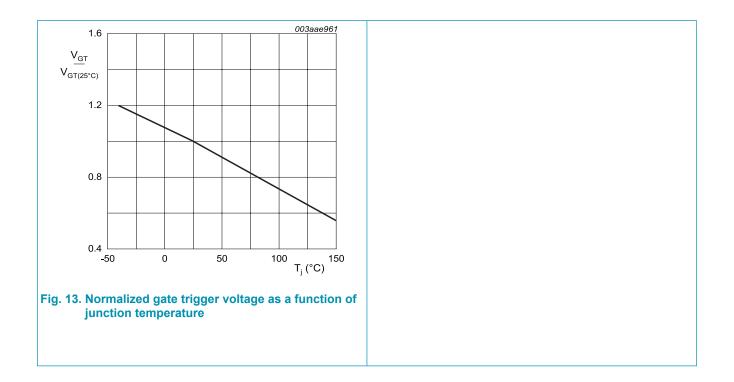
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	25	mA
I <sub>L</sub>	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T <sub>j</sub> = 25 °C; <u>Fig. 10</u>		-	-	15	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; <u>Fig. 10</u>		-	-	20	mA
		V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>		-	-	15	mA
		V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T2- G+; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>		-	-	20	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>		-	-	15	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 12</u>		-	1.4	1.6	V
V <sub>gt</sub>	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 13		-	0.7	1	V
		V <sub>D</sub> = 400 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 150 °C; Fig. 13		0.25	0.4	-	V
I <sub>D</sub>	off-state current	$V_{\rm D}$ = 800 V; T <sub>j</sub> = 25 °C		-	-	10	μA
		V <sub>D</sub> = 800 V; T <sub>j</sub> = 150 °C		-	-	0.5	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 800 V; T <sub>j</sub> = 25 °C		-	-	10	μA
		V <sub>R</sub> = 800 V; T <sub>j</sub> = 150 °C		-	-	0.5	mA
Dynamic	characteristics	1					1
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit		30	-	-	V/µs



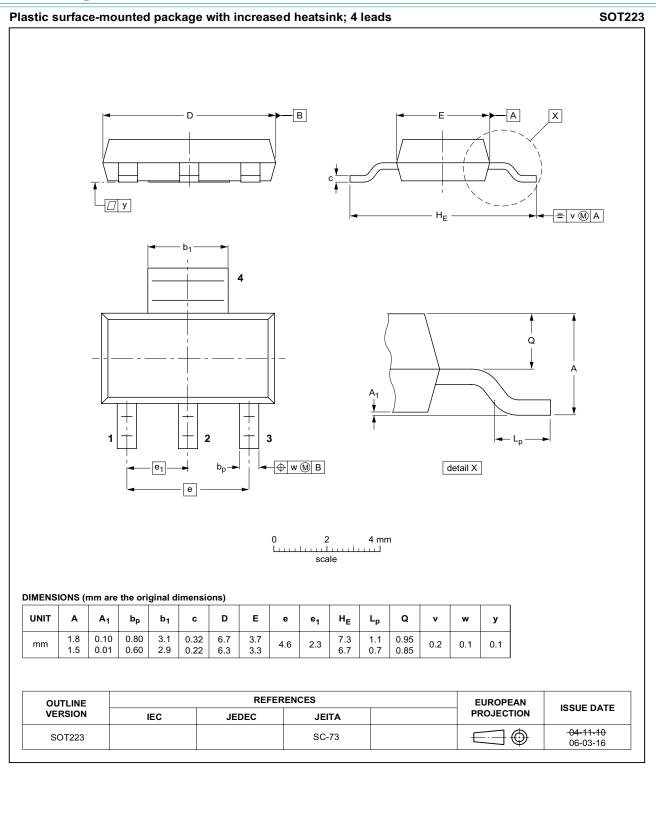
voltage

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BT234W-800ET 4Q Triac



### **11. Package outline**



### BT234W-800ET 4Q Triac

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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